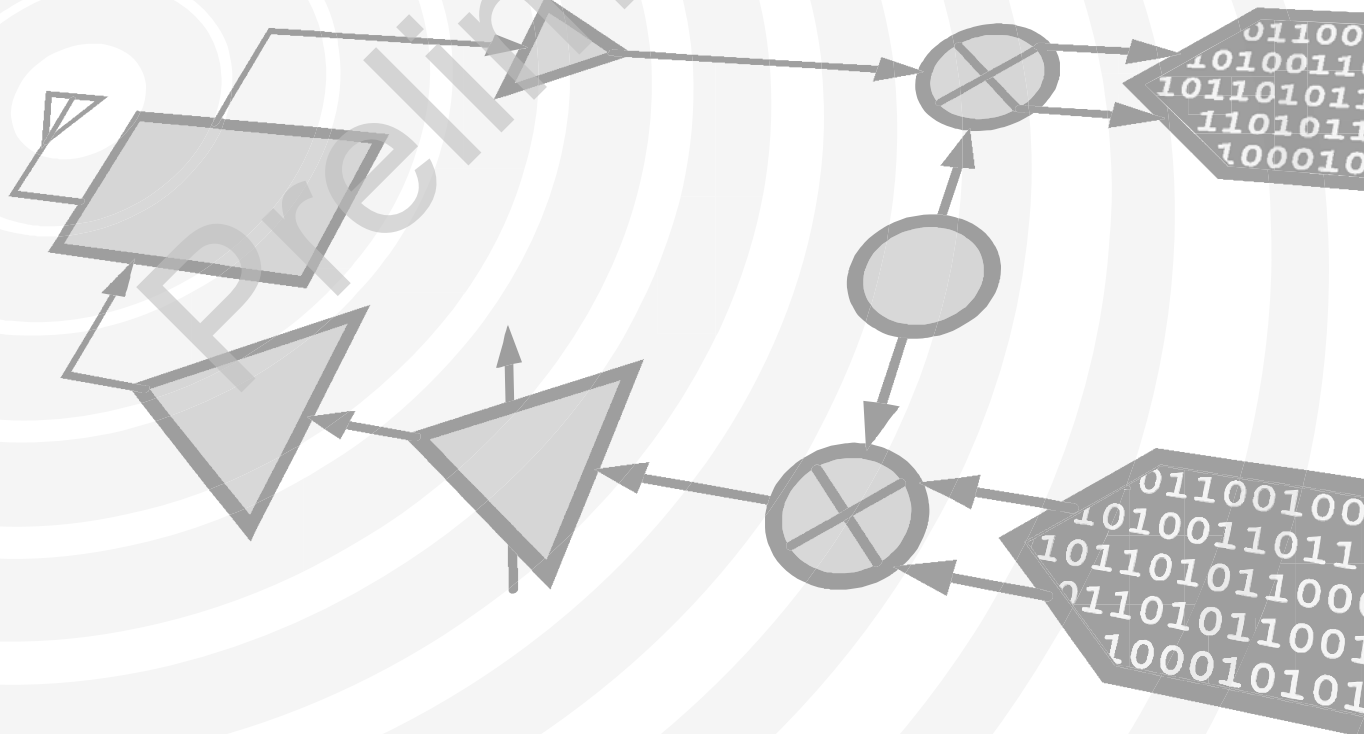


Analog Devices Welcomes Hittite Microwave Corporation



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Preliminary

GaAs MMIC FUNDAMENTAL MIXER, 14 - 26 GHz

Typical Applications

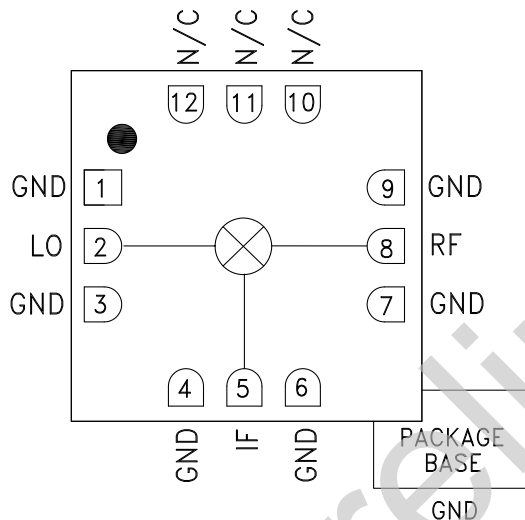
The HMC260ALC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use

Features

- Passive: No DC Bias Required
- Input IP3: +20 dBm
- LO/RF Isolation: 40 dB
- Wide IF Bandwidth: DC - 8 GHz
- 12 Lead Ceramic 3x3 mm SMT Package: 9mm²

Functional Diagram



General Description

The HMC260ALC3B is a general purpose double balanced mixer in a leadless RoHS compliant SMT package that can be used as an upconverter or downconverter between 14 and 26 GHz. This mixer requires no external components or matching circuitry. The HMC260ALC3B provides excellent LO to RF and LO to IF suppression due to optimized balun structures. The mixer operates with LO drive levels above +9 dBm. The HMC260ALC3B eliminates the need for wire bonding, allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $IF = 1\text{ GHz}$, $LO = +13\text{ dBm}^*$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF & LO		14 - 18			18 - 26		GHz
Frequency Range, IF		DC - 8			DC - 8		GHz
Conversion Loss		7.5	10.5		9	12	dB
Noise Figure (SSB)		7.5	10.5		9	12	dB
LO to RF Isolation	34	40		30	35		dB
LO to IF Isolation	24	30		24	35		dB
RF to IF Isolation	15	25		25	30		dB
IP3 (Input)		18			20		dBm
IP2 (Input)		50			50		dBm
1 dB Gain Compression (Input)		12			14		dBm

*Unless otherwise noted, all measurements performed as downconverter, $IF = 1\text{ GHz}$.

GaAs MMIC FUNDAMENTAL MIXER, 14 - 26 GHz

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	-2	17	xx	xx
1	18	0	38	50	78
2	82	74	71	65	84
3	xx	90	95	77	90
4	xx	xx	93	98	104

RF = 18 GHz @ -10 dBm
 LO = 17 GHz @ +13 dBm
 All values in dBc below the IF output power level.

Absolute Maximum Ratings

RF / IF Input	+15 dBm
LO Drive	+27 dBm
Channel Temperature	150 °C
Continuous Pdiss (Ta = 85 °C) (derate 3.95 mW/°C above 85 °C)	260 mW
Thermal Resistance (junction to ground paddle)	253 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing

